TVS Diode

Transient Voltage Suppressor Diode

ESD5V3U4U-HDMI

Uni-directional Ultra-low Capacitance ESD / Transient Protection Array

ESD5V3U4U-HDMI

Data Sheet

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Revision History	
Page or Item	**Subjects (major changes since previous revision)**
Revision 1.0, 2011-06-30	
all	data sheet conversion to Framemaker template

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Last Trademarks Update 2010-10-26

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Predefined Names

Name	Initial Cross-Reference
X-GOLD	**X-GOLD**
XMM	**XMM**

Definition of “Predefined Names”

Frequently used expressions, such as component names, file names, tools releases, version numbers, proprietary variables and software links, can be used in a similar way as user variables. However, they must be listed in a special table and **not** in the standard file “Variables”.

Correct Usage

Steps:

1. Insert all expressions into the left column of the above table.
2. Insert an initial Cross-Reference into the right column of the same row. The initial Cross-Reference is necessary to ensure that a single ID is used in all your documents using the “Predefined_Names.fm” file (Example: **X-GOLD** has the unique ID = CHDGHJGH).
3. Insert a Cross-Reference (Element “CrossReference”) into your document to the Element Identifier of the “Predefined_Names.fm” file. Set the output format of the Cross-Reference to “Variable” (example: X-GOLD).

Notes

1. *All documents in a project (such as XMM) and within a book should use the same file “Predefined Names”. This allows copying content between different documents. For this reason, local versions of “Predefined Names” must not be produced.*
2. *New definitions must be inserted in a new row. Never change existing definitions, as they might be used in other documents.*
3. *This file does not need to be included in your book, but it must be in the fm sub-folder of your document.*
4. *You can sort the above table with FrameMaker only if the initial cross-reference in the right column has been properly inserted. Otherwise, the table may only be sorted by hand, as the cross-references to your document would get lost.*

1 Uni-directional Ultra-low Capacitance ESD / Transient Protection Array

1.1 Features

- ESD / Transient protection of high speed data lines exceeding:
  - IEC61000-4-2 (ESD): ±20 kV (air / contact)
  - IEC61000-4-4 (EFT): 2.5 kV / 50 A (5/50 ns)
  - IEC61000-4-5 (surge): 3 A (8/20 µs)
- Maximum working voltage: V_R = 5.3 V
- Very low reverse current: I_R < 1 nA typ.
- Extremely low capacitance: 0.4 pF typ. (I/O to GND)
- Four-lines protection array with pad pitch = 0.5 mm
- Flow-through design for optimal PCB layout of differential lines
- Pb-free package (RoHS compliant) and halogen free package

1.2 Application Examples

- Protection of high speed digital interfaces like:
- HDMI 1.3, HDMI 1.4a, MHL, DisplayPort, S-ATA, DVI, MIPI, MDDI
- USB2.0, 10/100/1000 Ethernet, FireWire

2 Product Description

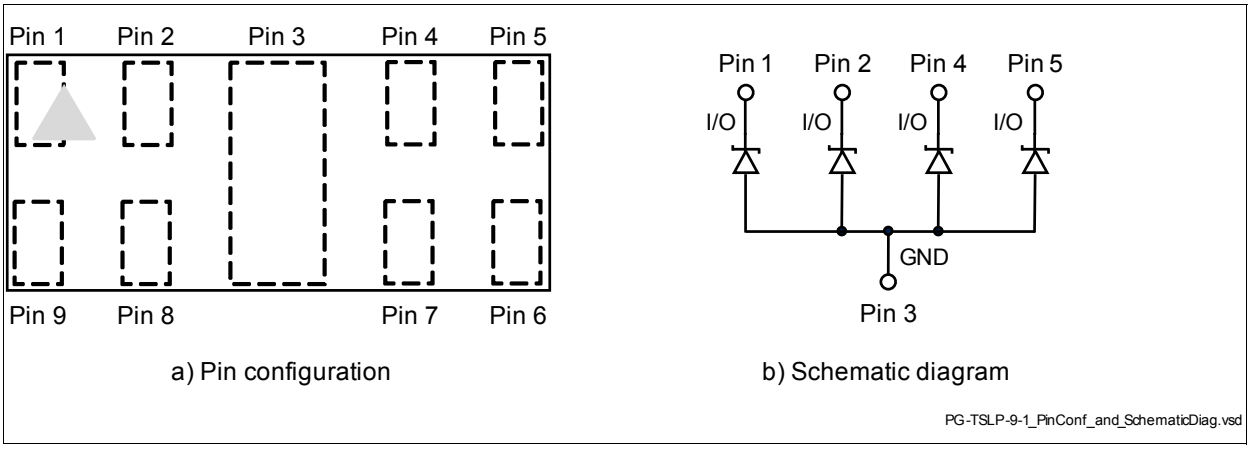

Figure 2-1 Pin Configuration and Schematic Diagram

Table 2-1 Ordering information

Type	Package	Configuration	Marking code
ESD5V3U4U-HDMI	PG-TSLP-9-1	4 lines, uni-directional	Z1

3 Characteristics

Table 3-1 Maximum Rating at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
ESD (air / contact) discharge[1)]	V_{ESD}	–	–	20	kV
Peak pulse current (t_p = 8/20 µs)[2)]	I_{PP}	–	–	3	A
Operating temperature range	T_{OP}	-40	–	125	°C
Storage temperature	T_{stg}	-65	–	150	°C

1) V_{ESD} according to IEC61000-4-2

2) I_{PP} according to IEC61000-4-5

3.1 Electrical Characteristics at T_A = 25 °C, unless otherwise specified

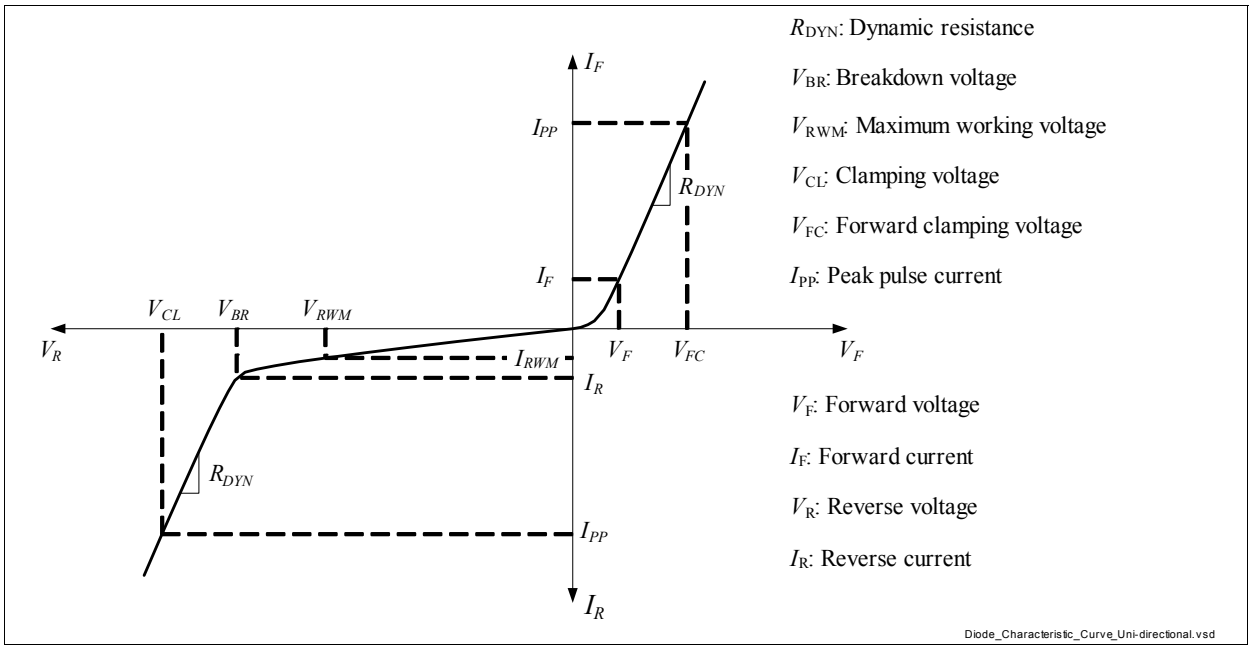

Figure 3-1 Definitions of Electrical Characteristics

Table 3-2 DC Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	V_{RWM}	–	–	5.3	V	
Breakdown voltage	V_{BR}	6	–	–	V	I_{BR} = 1 mA (I/O to GND)
Reverse current	I_R	–	<1	50	nA	V_R = 5.3 V (I/O to GND)

Table 3-3 RF Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Line capacitance[1)]	C_L	–	0.4	0.6	pF	V_R = 0 V, f = 1 MHz (I/O to GND)
Line capacitance[1)]	C_L	–	0.2	0.3	pF	V_R = 0 V, f = 1 MHz (I/O to I/O)

1) Total capacitance line to ground

Table 3-4 ESD Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage[1)]	V_{CL}	–	19	–	V	I_{PP} = 16 A (I/O to GND)
		–	28	–	V	I_{PP} = 30 A (I/O to GND)
Forward clamping voltage[1)]	V_{FC}	–	10	–	V	I_{PP} = 16 A (GND to I/O)
		–	17	–	V	I_{PP} = 30 A (GND to I/O)
Dynamic resistance[1)]	R_{DYN}	–	0.6	–	Ω	I/O to GND
		–	0.5	–		GND to I/O

1) Please refer to Application Note AN210 [1]. TLP parameter: Z_0 = 50 Ω, t_p = 100ns, t_r = 300ps, averaging window: t_1 = 30 ns to t_2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristic between I_{PP1} = 10 A and I_{PP2} = 40 A.

3.2 Typical Characteristics at T_A = 25°C, unless otherwise specified

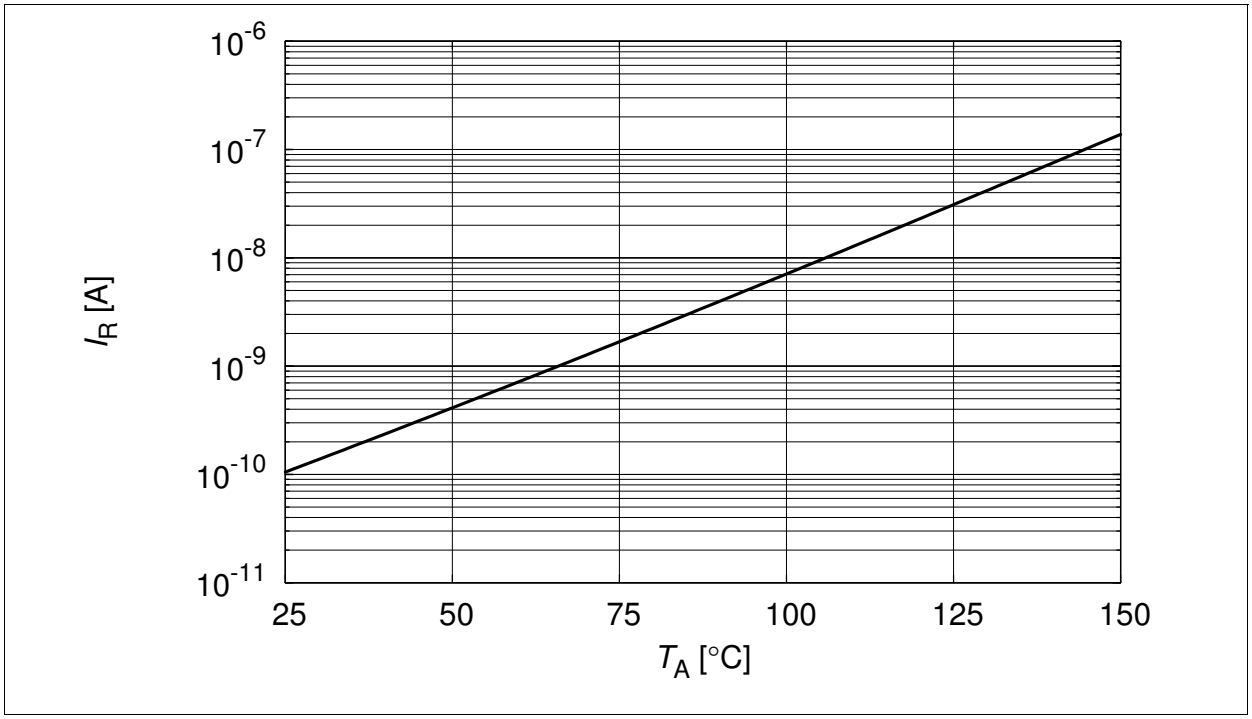

Figure 3-2 Reverse current: $I_R = f(T_A)$, V_R = 5.3 V, (I/O to GND)

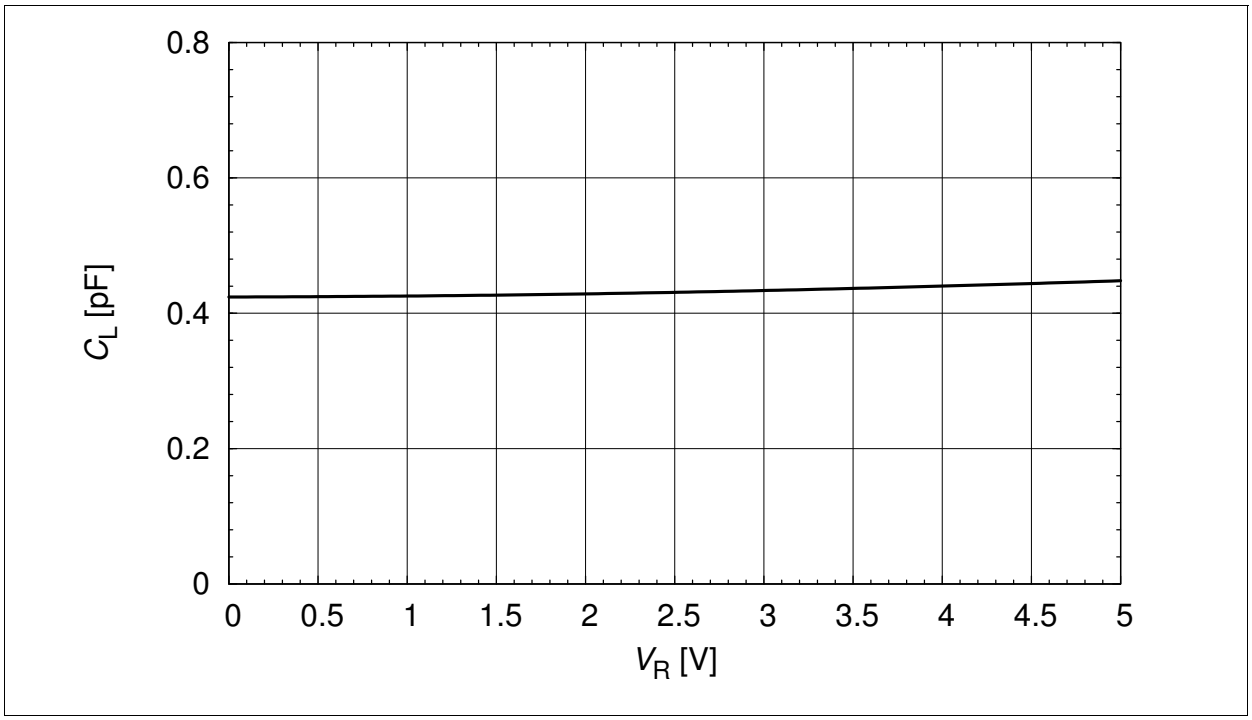

Figure 3-3 Diode capacitance: $C_L = f(V_R)$, (I/O to GND)

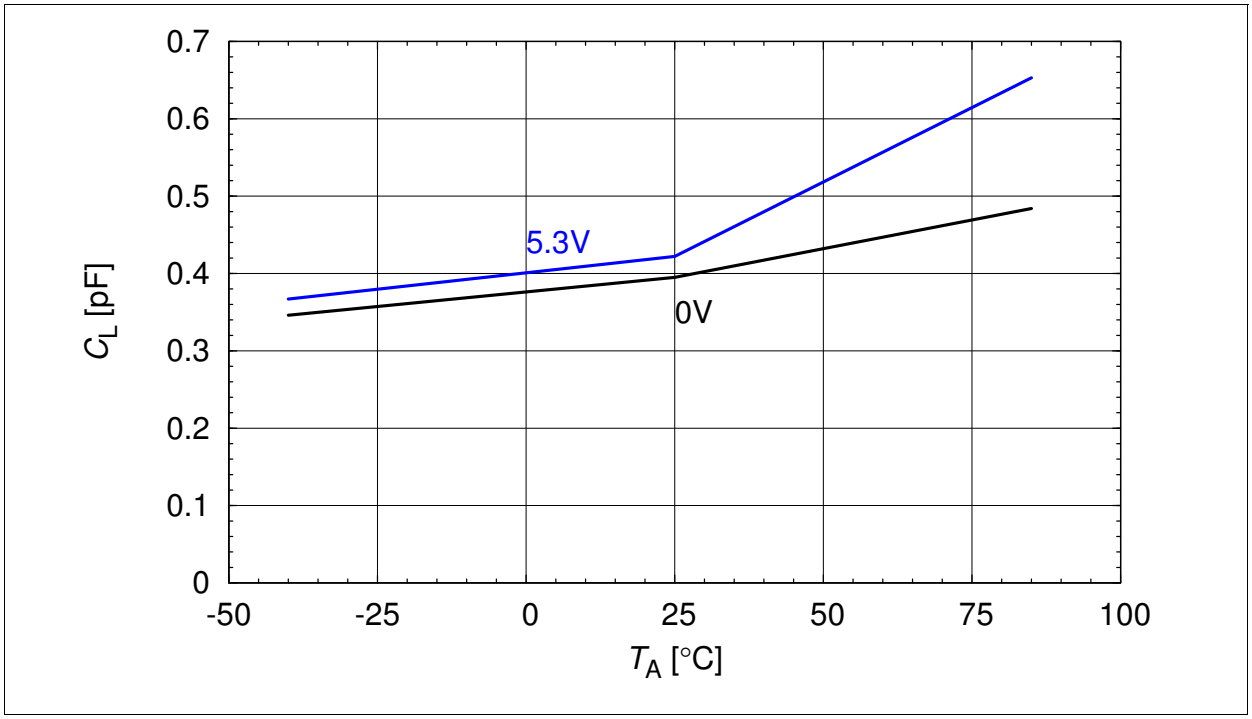

Figure 3-4 Line capacitance: $C_L = f(T_A)$

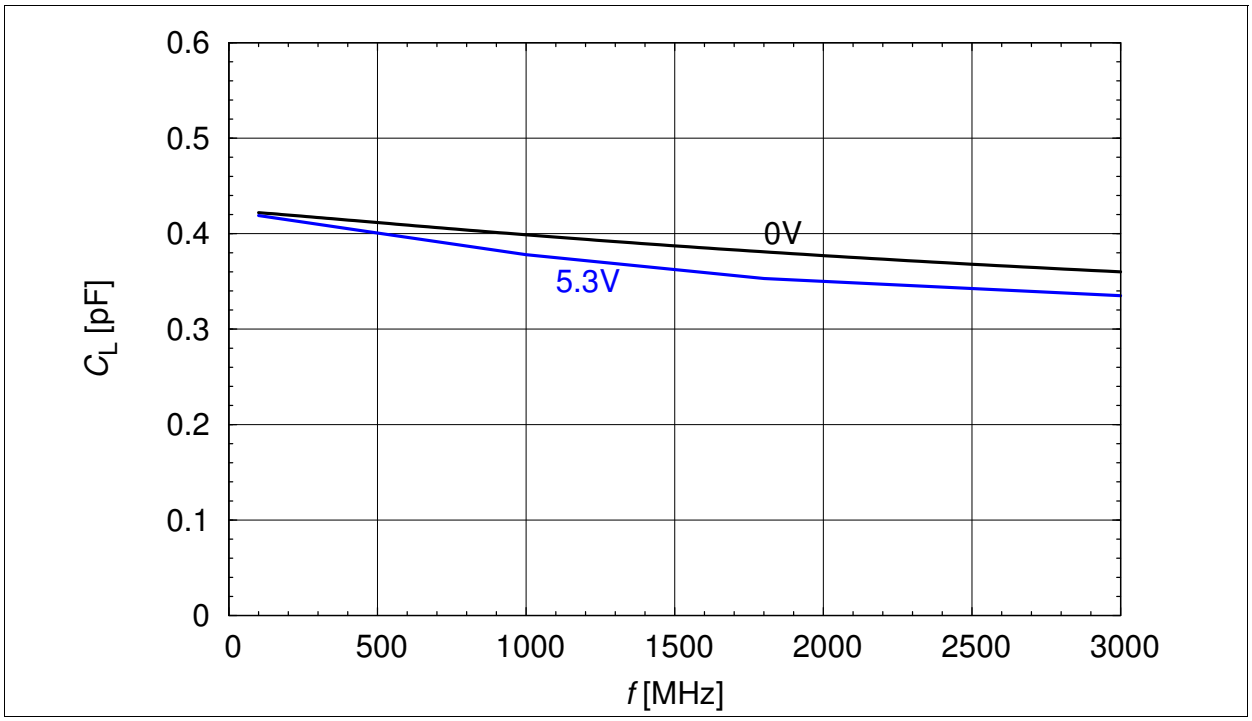

Figure 3-5 Line capacitance: $C_L = f(f)$, (I/O to GND)

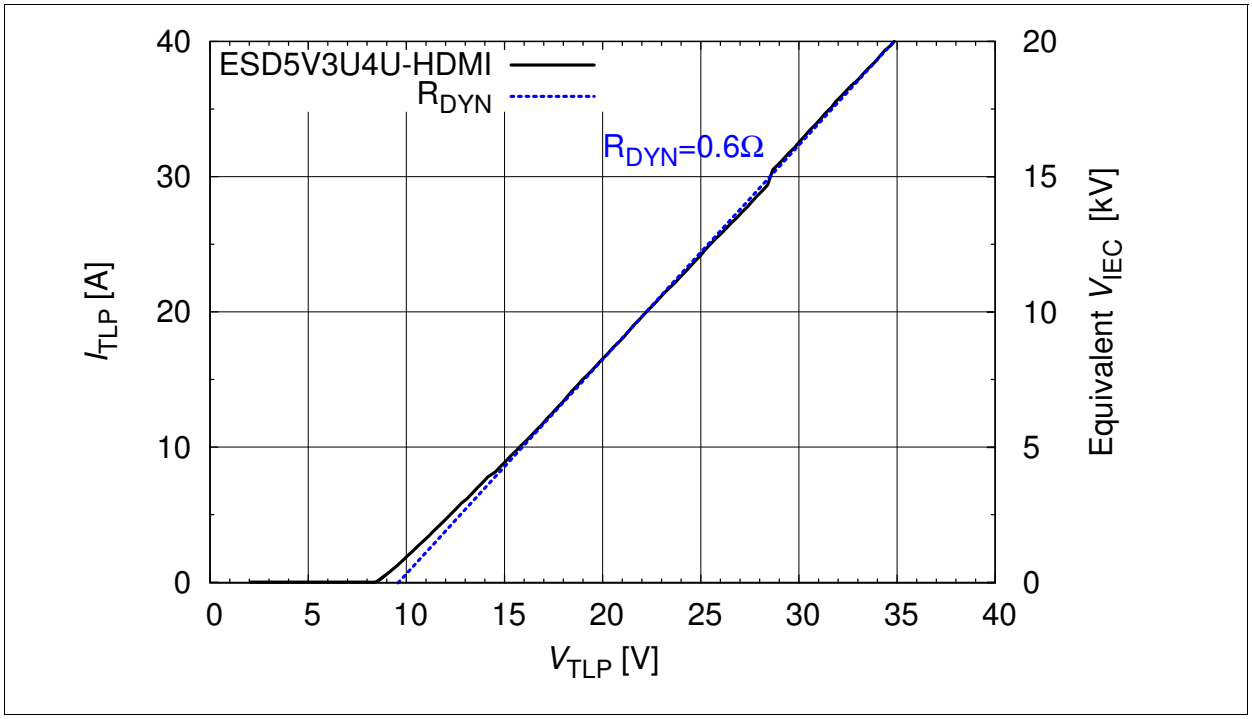

Figure 3-6 Forward clamping voltage: $I_{TLP} = f(V_{TLP})$, (GND to I/O) [1]

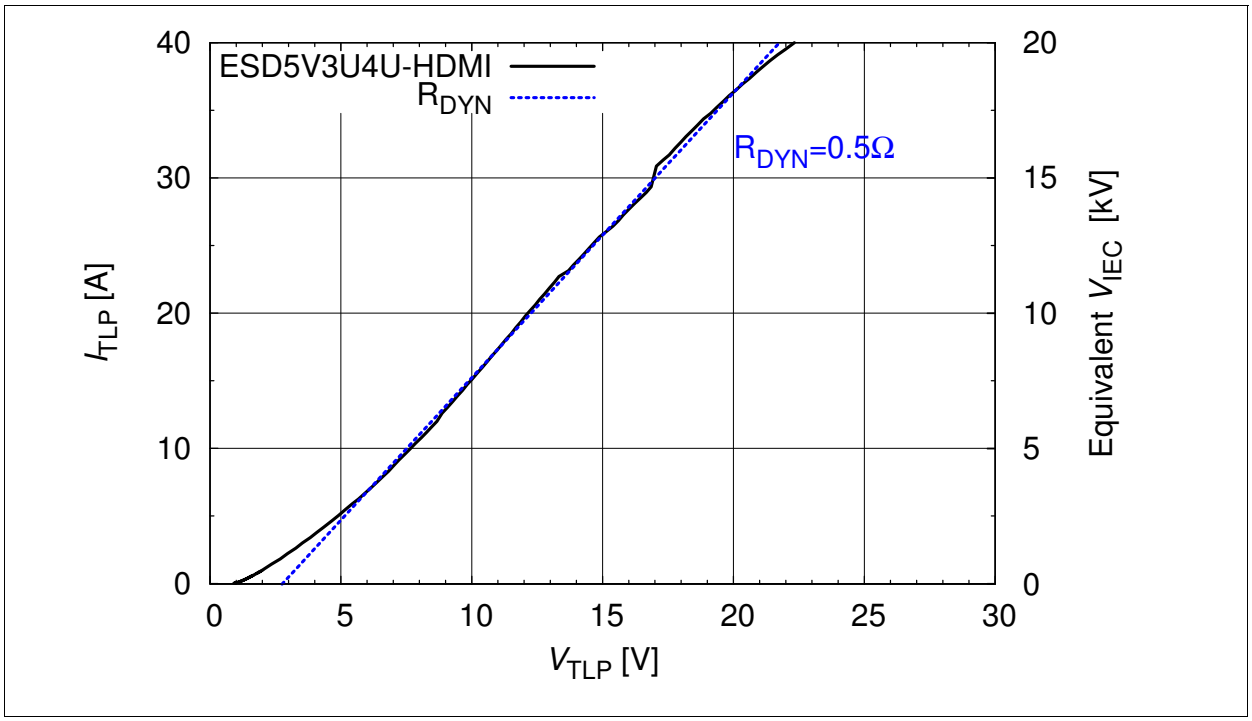

Figure 3-7 Reverse clamping voltage: $I_{TLP} = f(V_{TLP})$, (I/O to GND) [1]

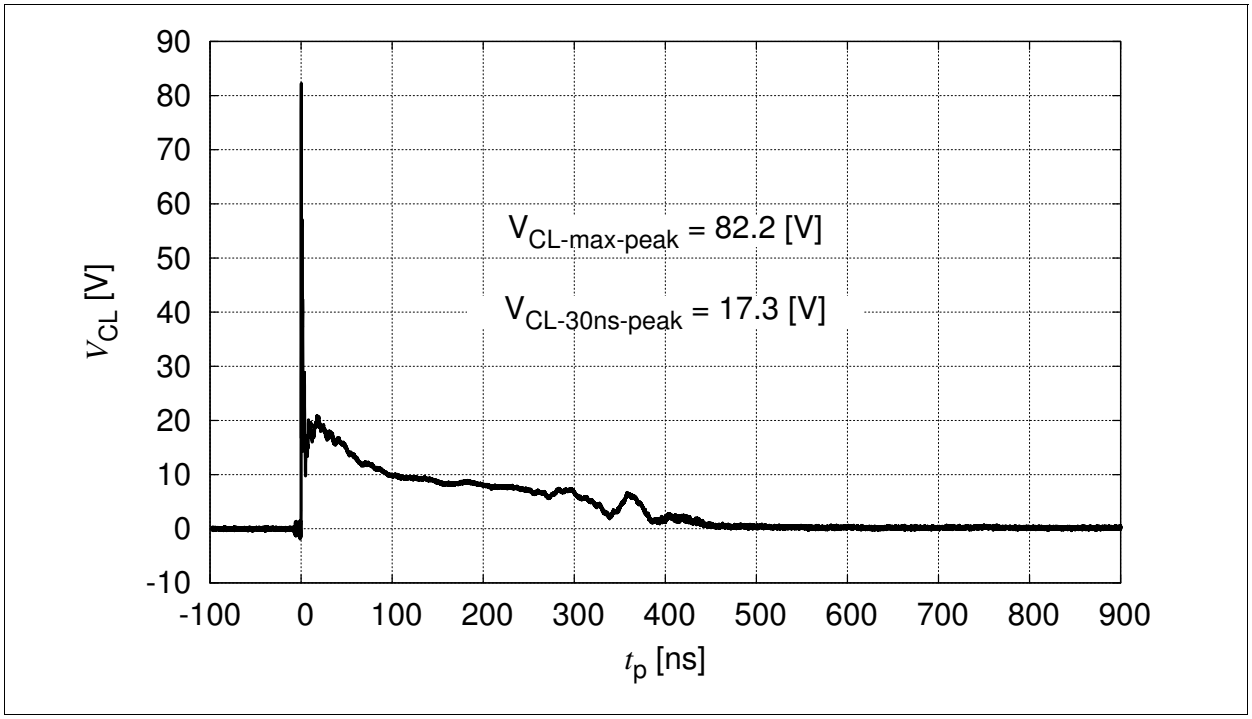

Figure 3-8 IEC61000-4-2 $V_{CL} = f(t)$, 8 kV positive pulse, (I/O to GND)

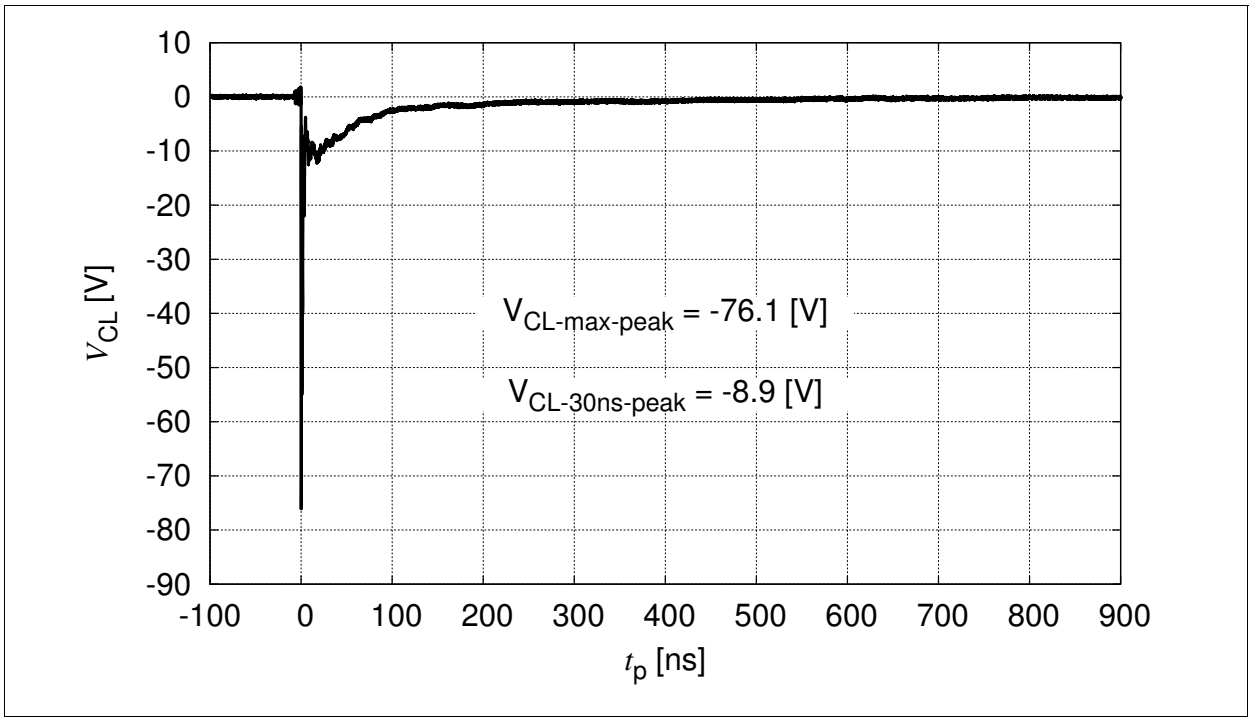

Figure 3-9 IEC61000-4-2 $V_{CL} = f(t)$, 8 kV negative pulse, (I/O to GND)

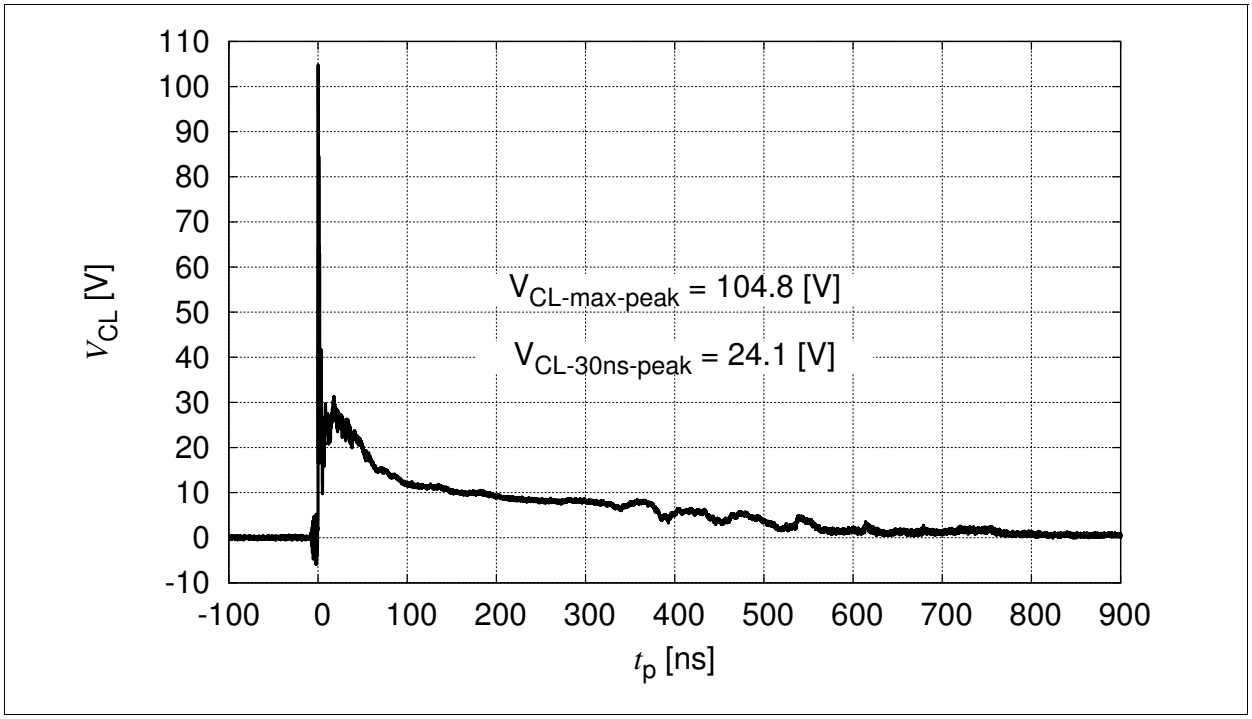

Figure 3-10 IEC61000-4-2 V_{CL} = $f(t)$, 15 kV positive pulse, (I/O to GND)

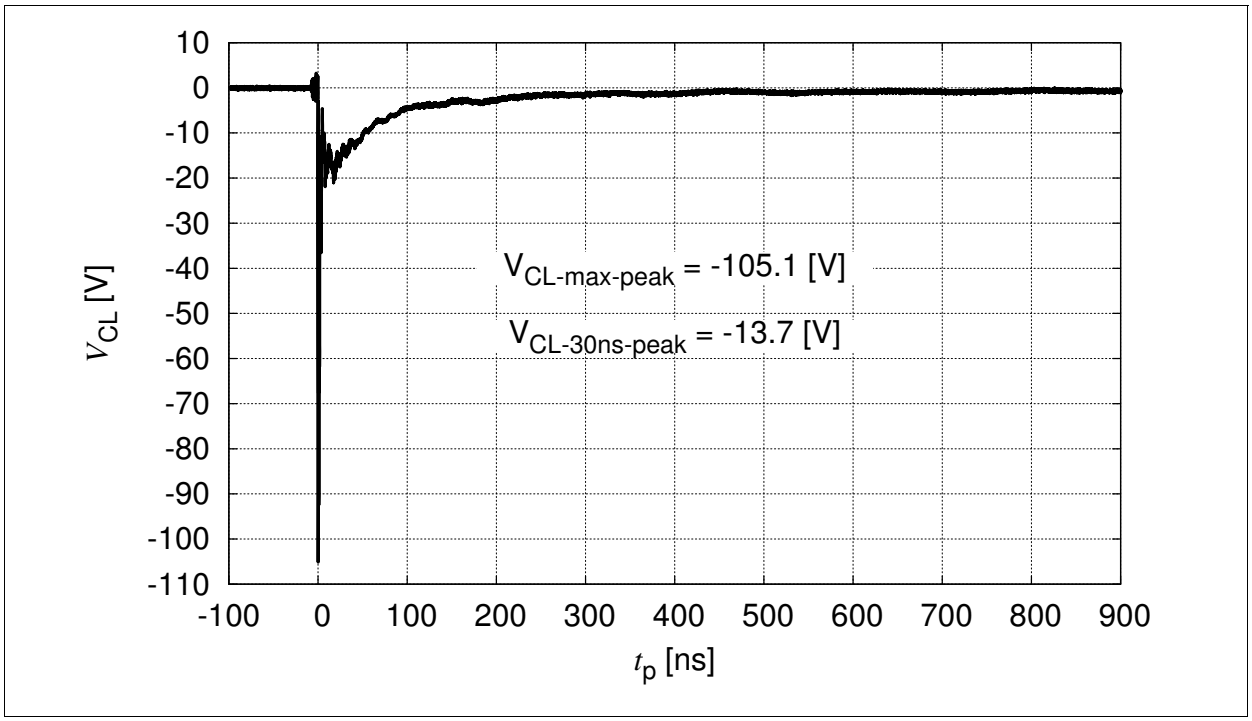

Figure 3-11 IEC61000-4-2 V_{CL} = $f(t)$, 15 kV negative pulse, (I/O to GND)

4 Application Information

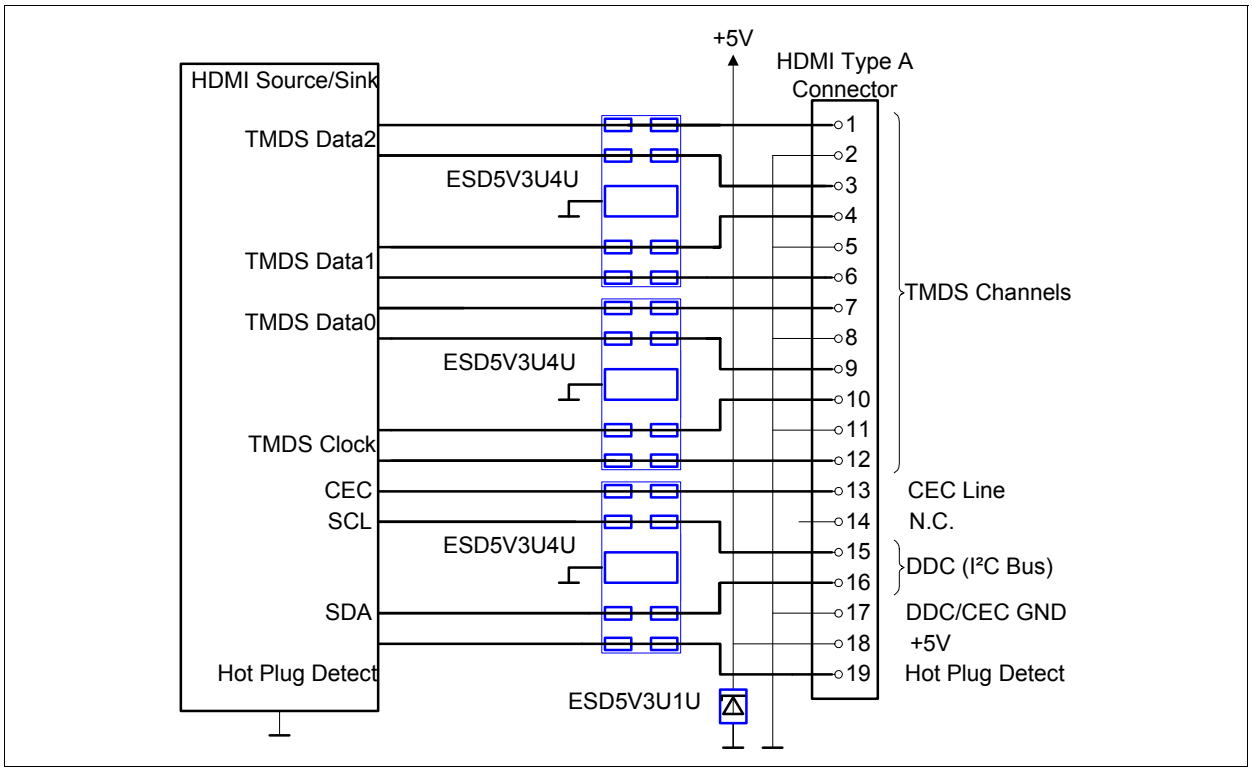

Figure 4-1 4 lines, uni-directional ESD5V3U4U-HDMI

For protection on the 5 V supply rail please refer to ESD5V3U1U- TVS diode data sheet.

5 Ordering Information Scheme (Examples)

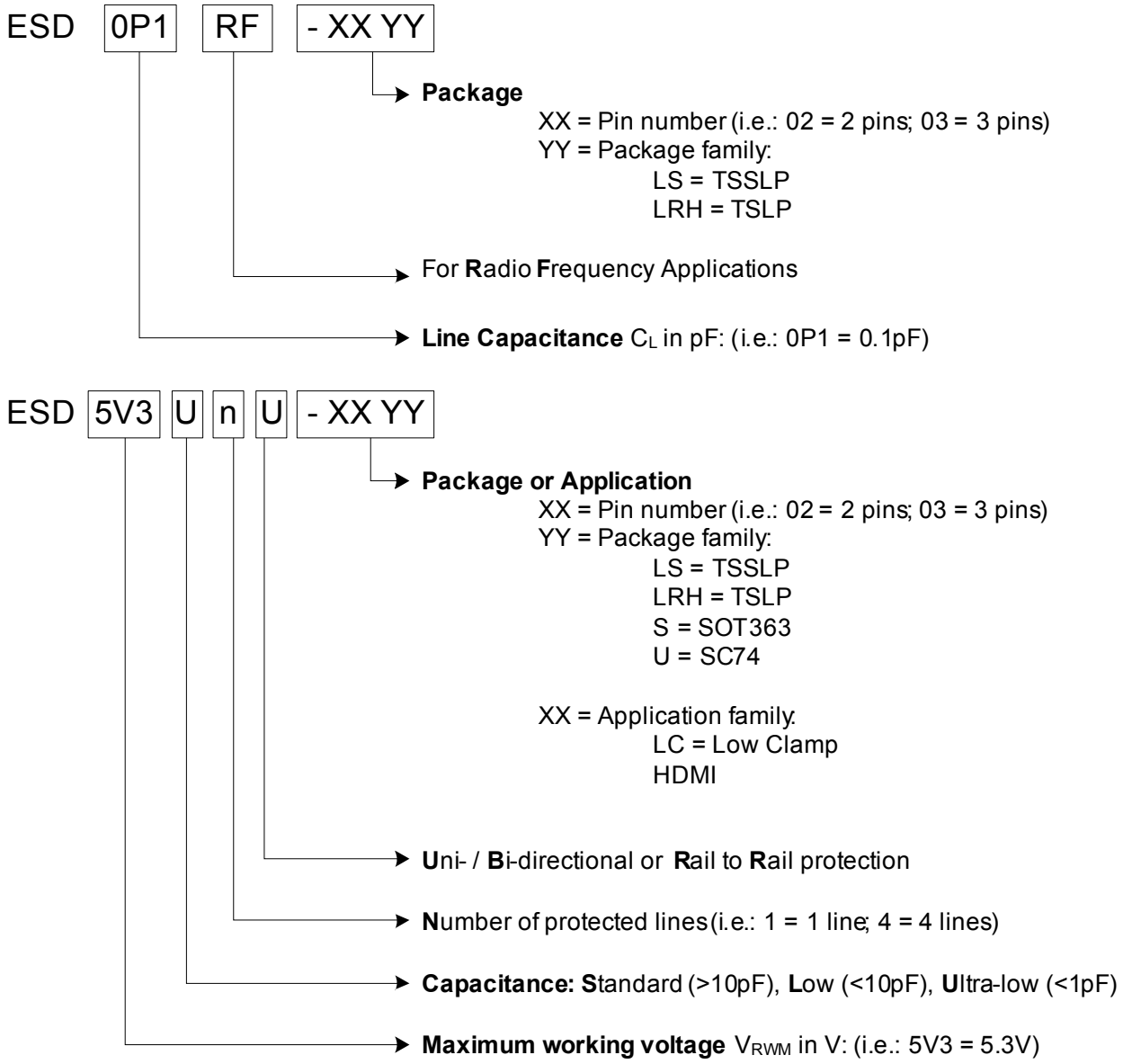

Figure 5-1 Ordering information scheme

6 Package Information

6.1 PG-TSLP-9-1

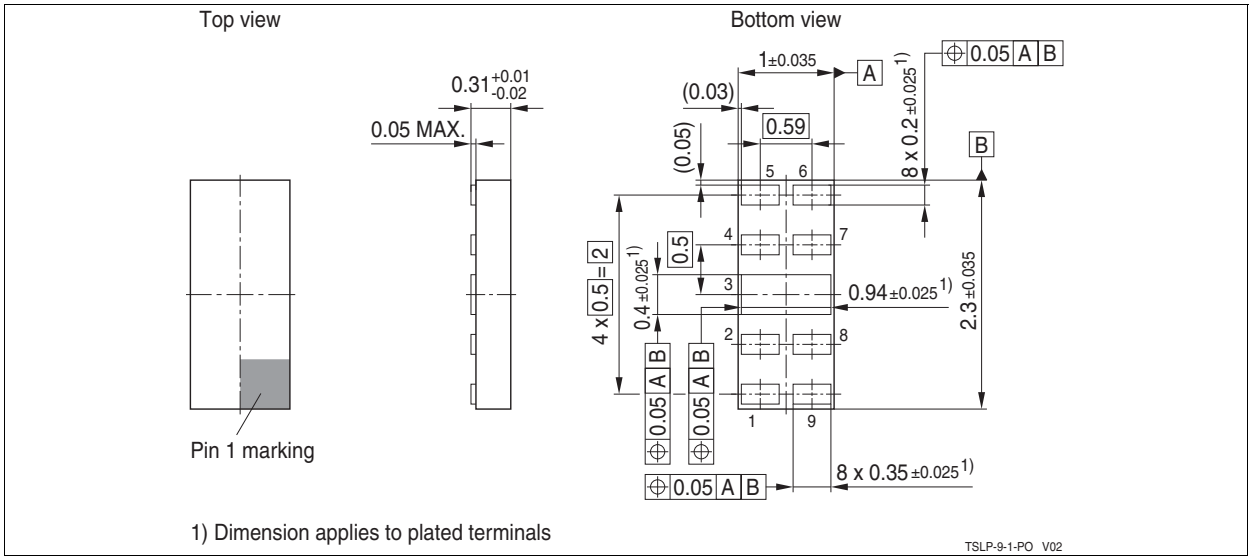

Figure 6-1 PG-TSLP-9-1: Package overview

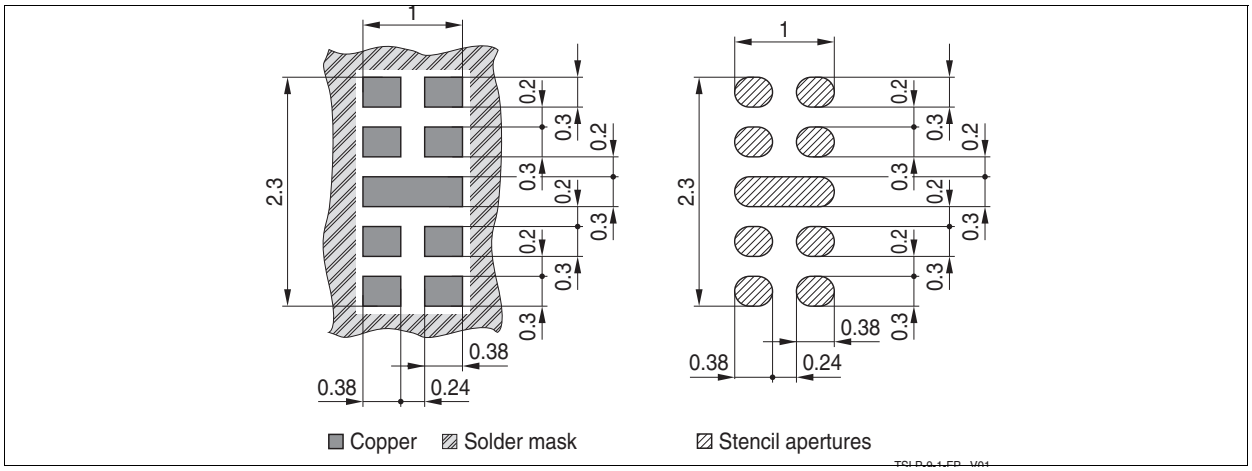

Figure 6-2 PG-TSLP-9-1: Footprint

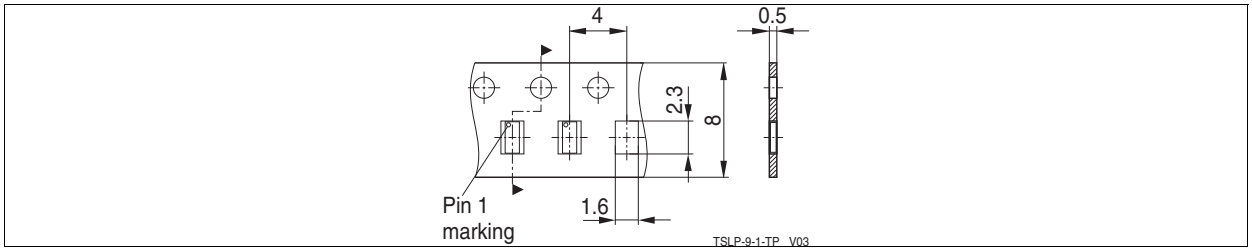

Figure 6-3 PG-TSLP-9-1: Packing

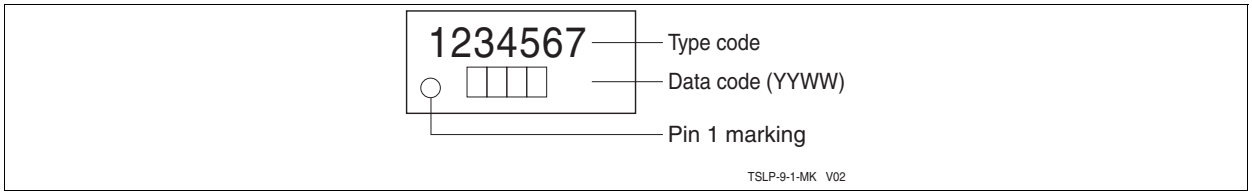

Figure 6-4 PG-TSLP-9-1: Marking (example)

References

[1] Infineon AG - **Application Note AN210**: Effective ESD Protection Design at System Level Using VF-TLP Characterization Methodology

Terminology

C_L	Line capacitance
DVI	Digital Visual Interface
EFT	Electrical Fast Transient
ESD	Electrostatic Discharge
HDMI	High Definition Multimedia Interface
I_{PP}	Peak pulse current
I_R	Reverse current
MDDI	Mobile Display Digital Interface
MHL	Mobile Display Digital Interface
MIPI	Mobile Industrial Processor Interface
RoHS	Restriction of Hazardous Substances Directive
S-ATA	Serial Advanced Technology Attachment
T_{OP}	Operation temperature
t_p	Pulse duration
T_{stg}	Storage temperature
USB	Universal Serial Bus
V_{BR}	Breakdown voltage
V_{CL}	Reverse clamping voltage
V_{ESD}	Electrostatic discharge voltage
V_{FC}	Forward Clamping Voltage
V_R	Reverse voltage
V_{RWM}	Maximum Reverse Working Voltage

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